TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62705P,TD62705F,TD62706P,TD62706F

6CH HIGH-VOLTAGE SOURCE DRIVER

The TD62705P, TD62705F and TD62706P, TD62706F are comprised of six source current transistor array.

These drivers are specifically designed for fluorescent display applications.

For proper operation, the substrate (SUB) must be connected to the most negative voltage.

FEATURES

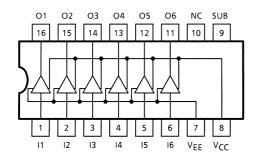
• High output voltage : $V_{CC} - V_{OUT} = 60 \text{ V (Min)}$

• Output current (single output) ∶ IOUT = -50 mA (Max)

• Input compatible with various types of logic TD62705P, TD62705F R_{IN} = 47 k Ω : 6~25 V PMOS, CMOS TD62706P, TD62706F R_{IN} = 10 k Ω : TTL, 5 V CMOS

Package type-P: DIP-16 pinPackage type-F: SOP-16 pin

PIN CONNECTION (TOP VIEW)

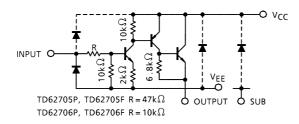


TD62705P TD62706P DIP16-P-300-2.54A TD62706F SOP16-P-225-1.27

Weight

DIP16-P-300-2.54A: 1.11 g (Typ.) SOP16-P-225-1.27: 0.16 g (Typ.)

SCHEMATICS (EACH DRIVER)



Note: The input and output parasitic diodes cannot be used as clamp diodes.



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC} - V _{EE}	30	V	
Supply Voltage		V _{CC} - V _{SUB}	60		
Output Voltage		V _{CC} - V _{OUT}	-60	V	
Input Voltage		V _{IN} - V _{EE}	V _{CC} - V _{EE}	V	
Output Current		lout	-50	mA / ch	
Input Current		I _{IN}	±10	mA	
Power Dissipation	Р	P _D (Note 2)	1.0	W	
Fower Dissipation	F	FD (Note 2)	0.625 (Note 1)		
Operating Temperature)	T _{opr}	-40~85	°C	
Storage Temperature		T _{stg}	-55~150	°C	

Note 1: On Glass Epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

Note 2: Delated above 25°C in the proportion 8.0 mw / °C (P Type), 5.0 mw / °C (F Type).

RECOMMENDED OPERATING CONDITIONS (Ta = $-40 \sim 85$ °C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT
	TD62705P TD62705F	V	V _{FF} = 0 V	6.0	_	25	V
Supply Voltage	TD62706P TD62706F	V _{CC}	VEE - 0 V	4.5	_	25	
		V _{SUB}	V _{CC} = 0 V	V _{OUT}	_	-55	
Output Voltage		V _{OUT}	V _{CC} = 0 V	0	_	-55	V
Output Current		lout	_	0	_	-40	mA / ch
Input Voltage	TD62705P TD62705F	V _{IN}	V _{EE} = 0 V, V _{CC} = 25 V	0	_	25	V
	TD62706P TD62706F			0	_	7	
Power Dissipation	Р	P _D	_	_	_	0.36	W
	F		On PCB (Note) —	_	0.325	v V

Note: On Glass Epoxy PCB (50 × 50 × 1.6 mm, Cu 50%)



ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CH	IARACTE	RISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Input Voltage	"H" Level	TD62705P TD62705F	- V _{IH}	1	V _{EE} = 0 V	6.0	_			
		TD62706P TD62706F			V _{EE} = 0 V	2.2	_	1	V	
	"L" Level	TD62705P TD62705F		1	V _{EE} = 0 V		_	2.2	v	
	L Level	TD62706P TD62706F	'"		V _{EE} = 0 V		_	0.8		
Input "H" Lev Current "L" Lev	"H" I eve	TD62705P TD62705F	- I _{IH} 2	2	V _{EE} = 0 V, V _{IN} = 6.0 V		0.11	0.16	- mA	
	II Level	TD62706P TD62706F		V _{EE} = 0 V, V _{IN} = 2.4 V	_	0.12	0.18	ША		
	"L" Level		I _{IL}	2	V _{EE} = V _{IN} = 0 V, V _{CC} = 25 V		_	±1	μΑ	
Output Leak	age Curre	nt	I _{CEX}	3	V _{EE} = 0 V, V _{CC} = 25 V V _{IN} = V _{IL MAX} . I _{OUT} = -30 V		_	-100	μΑ	
Collector-E	ctor–Emitter Saturation Voltage $V_{CE (sat)}$ $V_{EE} = 0 \text{ V}, V_{CC} = V_{CC MIN}.$ $V_{IN} = V_{IH MIN}.$ $I_{OUT} = -40 \text{ mA}$		_	_	V _{CC} - 2.5	V				
Supply Current (Output On)		TD62705P TD62705F	laa	1	V _{EE} = 0 V, V _{CC} = 25 V V _{IN} = V _{IN MAX} , I _{OUT} = 0 mA	_	_	32	- mA	
		TD62706P TD62706F		'	V _{IN} = V _{IN MAX.} I _{OUT} = 0 mA	_	_	25	111/1	
Turn-On Delay		t _{ON}	- 5	$R_1 = 1.4 \text{ k}\Omega, C_1 = 15 \text{ pF}$		0.2	_	μs		
Turn-Off Delay		t _{OFF}		1.4 κ.22, ΟΕ = 10 μι	_	1.5	_	μs		

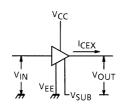
3

TEST CIRCUIT

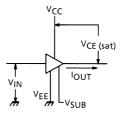
1. VIH, VIL, ICC

2. I_{IH}, I_{IL}

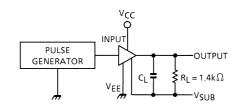
3. I_{CEX}



4. V_{CE (sat)}



5. ton, toff



C_L = 15 pF (Includes probe and jig capacitance)

INPUT CONDITION

TYPE NAME	V _{IN}	V _{CC}	V _{SUB}
TD62705P, TD62705F	0-9V	25V	-30
TD62706P, TD62706F	0-3V	25V	-30

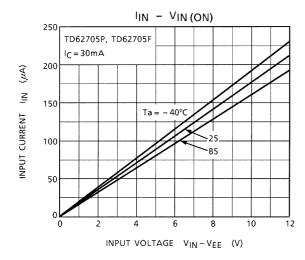
 V_{IN} : Pulse Width 50 μs Duty Cycle 50% $t_{\Gamma} \le 5$ ns $t_f \le 10$ ns

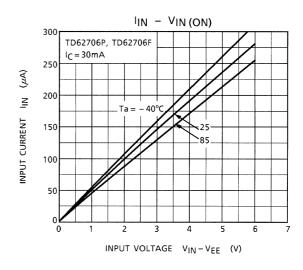
PRECAUTIONS for USING

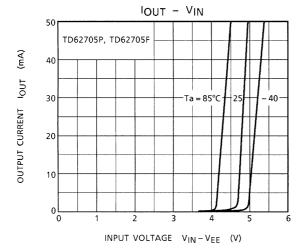
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

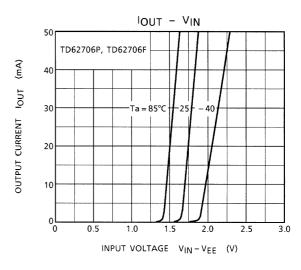
Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

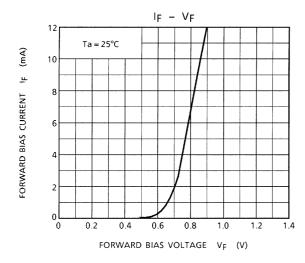
Utmost care is necessary in the design of the output line, V_{CC} and GND (SUB, V_{EE}) line since IC may be destroyed due to short–circuit between outputs, air contamination fault, or fault by improper grounding.

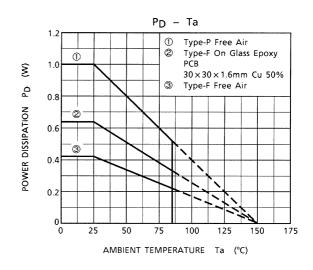






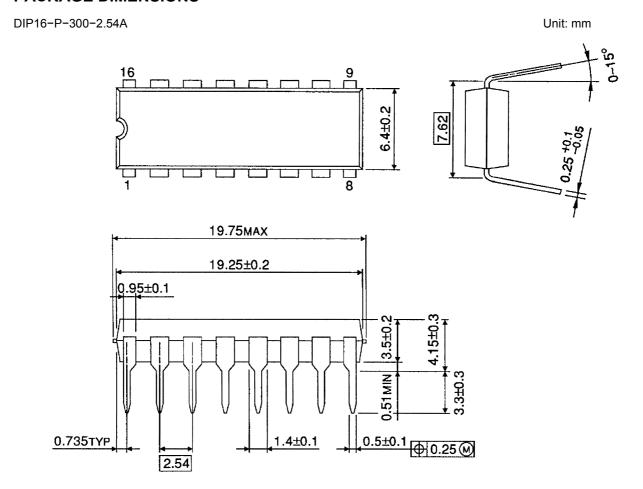






5

PACKAGE DIMENSIONS



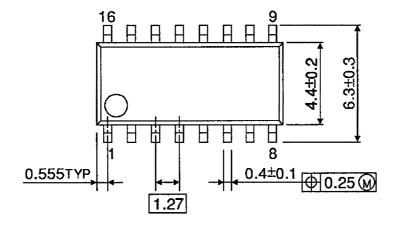
6

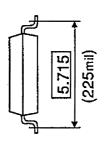
Weight: 1.11 g (Typ.)

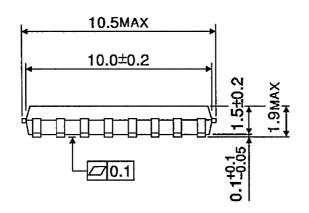
PACKAGE DIMENSIONS

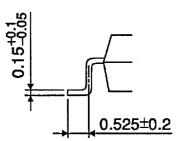
SOP16-P-225-1.27

Unit: mm









Weight: 0.16 g (Typ.)

RESTRICTIONS ON PRODUCT USE

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